

SANYO Semiconductors DATA SHEET



Monolithic Linear IC For Use in TV/VTR Applications VIF/SIF Signal Processing IC

Overview

The LA75501V is an adjustment free VIF/SIF signal processing IC for PAL TV/VCR. It supports 38MHz, 38.9MHz, and 39.5MHz as the IF frequencies, as well as PAL sound multi-system (M/N,B/G, I, D/K), and contains an on-chip sound carrier trap and sound carrier BPF. To adjust the VCO circuit, AFT circuit, and sound filter, 4MHz external crystal or 4MHz external signal is needed.

Function

- VIF Block: VIF Amplifier, PLL Detector, IF AGC, RF AGC, Equalizer, amplifier, Buzz Canceller, SIF Trap, Digital AFT, FLL, 4MHz X'tal oscillation
- 1st SIF Block: 1st SIF Amplifier, 1st SIF Detector, 1st SIF AGC
- SIF Block: Limiter Amplifier Down Converter, PLL FM Detector SIF PLL SIF VCO, SIF BPF
- Others: IF SW (38.9MHz, 38MHz), SIF4 System SW (B/G, I, D/K, M/N), IFAGC 2nd filter

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Supply voltage	V _{CC}		7	V
Circuit voltage	V ₁₆		V _{CC}	V
	V ₁₈		V _{CC}	V
Circuit Current	I ₃₀		-1	mA
	I ₁₇		+0.5	mA
	1 ₆		-10	mA
	I ₄		-3	mA
Allowable power dissipation	Pd max	Ta≤80°C *	500	mW
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

* Mounted on a board : 65×72×1.6mm³, paper phenol board.

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Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		5.0	V
Operating supply voltage	V _{CC} op		4.5 to 6.0	V

Electrical Characteristics at Ta = 25° C, V_{CC} = 5V, fp = 38.9MHz

VIF Block

Parameter	Symbol	Conditions		Ratings		Unit
i didilicitor	Cymbol	Conditions	min	typ	max	Onit
Circuit current	I ₂₁			64.0	73.6	mA
Maximum RF AGC voltage	V ₁₇ H	Collector load 30k VC2 = 9V	8.5	9		V
Minimum RF AGC voltage	V ₁₇ L		0.0	0.3	0.7	V
Input sensitivity	vi		33	39	45	dBµV
AGC range	GR		58			dB
Maximum allowable input	Vi max		92	97		dBµV
No-signal video output voltage	V ₆		2.9	3.3	3.7	V
Sync. Signal tip voltage	V ₆ tip		0.9	1.2	1.5	V
Video output amplitude	VO		1.5	1.8	2.1	Vp-p
Video S/N	S/N	B/G	48	52		dB
C-S best	IC-S	PS = 10dB	26	32	38	dB
Differential gain	DG	80dBµ, 87.5% MOD		5	10	%
Differential phase	DP	80dBµ, 87.5% MOD		2	10	°C
Black noise threshold voltage	V _{BTH}			0.7		V
Black noise clamp voltage	V _{BCL}			1.8		V
VIF input resistance	Ri			2.5	3.0	kΩ
VIF input capacitance	Ci			3	6	PF
Maximum AFT voltage	V ₁₆ H		4.3	4.7	5.0	V
Minimum AFT voltage	V ₁₆ L		0	0.2	0.7	V
AFT tolerance 1	dfa1	f = 38.9MHz		±35	±70	KHz
AFT tolerance 2	dfa2	f = 38.0MHz		±35	±70	KHz
ATF detection sensitivity	sf	$R_L = 100 k / / 100 K \Omega$	30	<u>⊥</u> 00 55	±10 80	mV/kHz
AFT Dead Zone	fda			30	60	MHz
APC pull-in range (U)	fpu		1.5	2.0	00	MHz
APC pull-in range (L)	fpl		1.5	2.0		MHz
VCO maximum	dfu		1.5	2.0		MHz
variable range (U)	ulu		1.5	2.0		
VCO maximum	dfl		1.5	2.0		MHz
variable range (L)						
VCO control sensitivity	β		2.0	4.0	8.0	kHz/mV
N Trap 1 (4.5M)	NT1		-30	-35		dB
N Trap 2 (4.8M)	NT1-1		-19	-24		dB
B/G Trap 1 (5.5M)	BT1		-27	-32		dB
B/G Trap 2 (5.85M)	BT1-1		-20	-25		dB
l Trap 1 (6.0M)	IT1		-25	-30		dB
l Trap 2 (6.55M)	IT1-1		-15	-20		dB
D/K Trap1 (6.5M)	DT1		-25	-30		dB
Group delay 1 NTSC (3.0M)	ngd1		30	60	90	ns
Group delay 1-1 NTSC (3.5M)	ngd1-1		160	230	300	ns
Group delay 2 B/G (4M)	bgd2		70	100	130	ns
Group delay 2-1 B/G (4.4M)	bgd2-1		160	230	300	ns
Group delay 3 I (4M)	bgd3		20	50	80	ns
Group delay 3-1 I (4.4M)	bgd3-1	1	60	90	120	ns
Group delay 4 D/K (4M)	bgdd 1 bgd4		0	30	60	ns
Group delay 4-1 D/K (4.4M)	bgd4-1		10	40	70	ns

1st SIF Block

Deremeter	Sumbol	Conditions	Ratings			Unit
Parameter	Symbol	Conditions	Conditions min		max	Unit
Conversion gain	VG	$fp-5.5MHz, Vi = 500\mu V$	26	32	36	dB
SIF carrier output level	So	Vi = 10mV		100		mVrms
1st SIF maximum input	Si max	So±2dB		106		dBμV
1st SIF input resistance	R _i s			2.0	2.4	KΩ
1st SIF input capacitance	C _i s			3	6	PF

SIF Block

Deremeter	Querra ha a l	Quanditiona		1.1			
Parameter	Symbol	Conditions	min typ		max	Unit	
Limiting sensitivity	Vi (lim)	f = 5.5MHz	46	52	58	dBμV	
FM detector output voltage	V _O (FM)	$\Delta F = \pm 30$ kHz at 400Hz	480	600	750	mVrms	
AM rejection ratio	AMR	AM = 30% at 400Hz	50	60		dB	
Distortion	THD	$f = 5.5MHz \Delta F = \pm 30kHz$		0.3	1.0	%	
FM detector output S/N	S/N (FM)	DIN. Audio	55	60		dB	
BPF 3dB band width	BW			±100		kHz	
PAL de-emphasis	Pdeem	fm = 3kHz		-3		dB	
NTSC de-emphasis	Ndeem	fm = 2kHz		-3		dB	
PAL/NT Audio voltage gain difference	GD			6		dB	

Others

Parameter	Cumbal	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min		max	Unit	
Minimum 4MHz level	X ₄ MIN	Terminal value	80	86	92	dBμ	
(at external input)							
SIF system SW threshold voltage	V ₁₃			1.4		V	
	V ₁₄						
IF system SW threshold voltage	V ₁₅				270	KΩ	
Split/Inter SW	V ₂₀			0.5		V	

System Changeover

SW/SIF system SW

The SIF system can be changed over by setting A (pin 13) and B (pin 14) to GND and the open state respectively.

А	В	B/G	I	D/K	M/N	FM DET LEVEL	De-emphasis
GND	GND				0	6dB	75µs
GND	OPEN			0		0dB	50µs
OPEN	GND		0			0dB	50µs
OPEN	OPEN	0				0dB	50µs

Note: 'O' indicates that the system is selected.

IF system SW

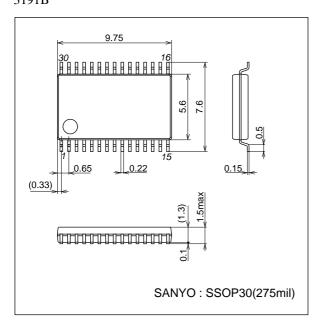
The IF frequency is selected 38.9MHz mode with the pin 15 (crystal oscillation) open. The IF frequency is selected 38MHz mode by adding $220K\Omega$ between the pin 15 and GND.

Inter carrier SW

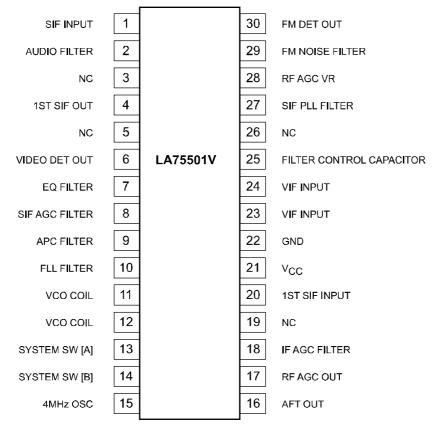
Inter-carrier is selected by setting the 1st SIF input (pin 20) to GND.

Package Dimensions

unit : mm 3191B

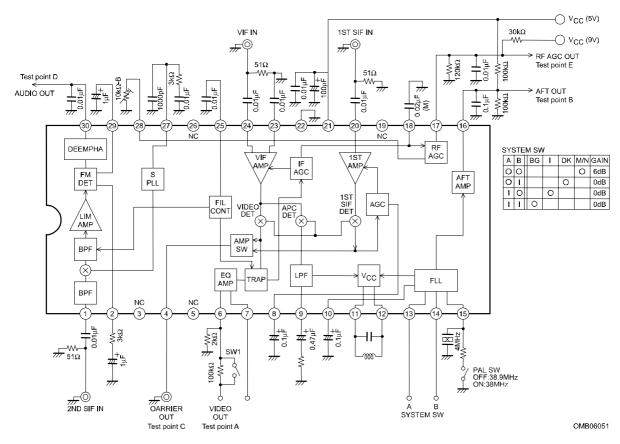


Pin Assignment

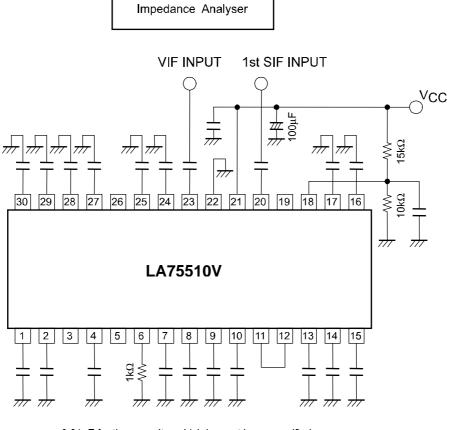


OMP06135





Input Impedance Test Circuit



0.01µF for the capacitor which has not been specified.

OMB06050

Test Conditions

- V1. Circuit current [l₂₁]
 - (1) External AGC ($V_{18} = 1.5V$)
 - (2) RF AGC VR MAX
 - (3) Connect an ammeter to the V_{CC} and measure the incoming current to pin 17.

V2. V3. Maximum RF AGC voltage, Minimum RF AGC voltage [V17H, V17L]

- (1) Internal AGC
- (2) Input a 38.9MHz, 10mVrms, continuous wave to the VIF input pin.
- (3) Adjust the RF AGC VR (resistance max.) and measure the maximum RF AGC voltage.
- (4) Adjust the RF AGC VR (resistance min.) and measure the minimum RF AGC voltage. (3), (4) Measuring point F

V4. Input sensitivity [Vi]

- (1) Internal AGC
- (2) fp = 38.9MHz 400Hz 40% AM (VIF input)
- (3) Turn off the SW1 and put $100k\Omega$ through.
- (4) Measure the VIF input level at which the 400Hz detection output level at test point A becomes 0.7Vp-p.
- V5. AGC range [GR]
 - (1) Apply the V_{CC} voltage to the external AGC, If AGC (pin 18).
 - (2) In the same manner under the same conditions as for V4 (input sensitivity), measure the VIF input level at which the detection output level becomes 0.7Vp-p. Vil *Vi: Input sensitivity

(3) GR =
$$20\log \frac{\text{Vil}}{\text{Vi}} \text{dB}$$

V6. Maximum allowable input [Vi max]

- (1) Internal AGC
- (2) fp = 38.9MHz 15kHz 78% AM (VIF input)
- (3) VIF input level at which the detection output level at test point A becomes video output (V_O) ± 1 dB.

V7. No-signal video output voltage [V6]

- (1) Apply the V_{CC} voltage to the external AGC, IF AGC (pin 18).
- (2) Measure the DC voltage of VIDEO output (A).

V8. Sync. signal tip voltage [V6tip]

- (1) Internal AGC
- (2) Input a 38.9MHz, 10mVrms, continuous wave to the VIF input pin.
- (3) Measure the DC voltage of VIDEO output (A).

V9. Video output level [VO]

- (1) Internal AGC
- (2) $fp = 38.9 MHz \ 15 kHz \ 78\% AM$
 - Vi = 10mVrms (VIF input)
- (3) Measure the peak value of the detection output level at test point A. (Vp-p)

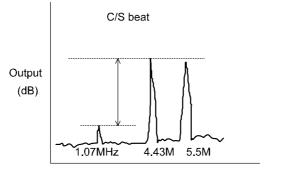
V10. Video S/N [S/N]

- (1) Internal AGC
- (2) fp = 38.9MHz CW = 10mVrms (VIF input)
- (3) Measure the noise voltage at test point A in RMS volts through a 10kHz to 4MHz band-pass filter. Noise voltage (N)

(4)
$$S/N = 20\log \frac{Video voltage (Vp-p)}{N (Vrms)} = 20\log \frac{1.12Vp-p}{N(Vrms)}$$
 (dB)

V11. C/S beat [lcs]

- (1) Apply DC voltage to the external AGC IF AGC (pin 18) and vary it.
- (2) fp = 38.9MHz CW;10mVrms
 - fc = 34.47MHz CW;10mVrms 10dB
 - fs = 33.4 MHz CW;10mVrms 10dB
- (3) Adjust the IF AGC (pin 18) voltage so that the output level at test point A becomes 1.3Vp-p.
- (4) Measure the difference between the levels for 4.43MHz and 1.07MHz components at test point A.



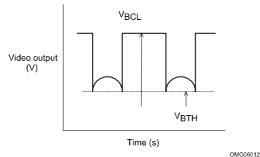
Frequency (MHz)

OMG06011

- V12.V13. Differential gain, differential phase [DG, DP]
 - (1) Internal AGC
 - (2) fp = 38.9MHz APL50% 87.5% Modulation video signal Vi = 10mVrms
 - (3) Measure the DG and DP at test point A.

V14.V15. Black noise threshold and clamp voltage [VBTH, VBCL]

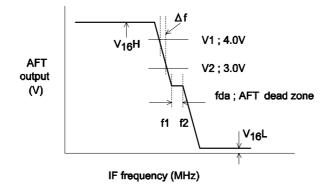
- (1) Apply DC voltage (1 to 3V) to the external AGC, IF AGC (pin 18) and adjust the voltage.
- (2) fp = 38.9MHz 400Hz 40% AM 10mVrms (VIF input)
- (3) Adjust the IF AGC (pin 18) voltage to operate the noise canceller.
 - Measure the VBTH, VBCL at test point A.



V16. V17. VIF input resistance, input capacitance [R_j, C_j]

- (1) External AGC ($V_{18} = 2V$)
- (2) Referring to the Input Impedance Test Circuit, measure Ri and Ci with an impedance analyzer.

- V18. V19. Maximum, minimum AFT voltage, AFT detection sensitivity [V₁₆H, V₁₆L]
 - (1) Internal AGC
 - (2) fp = 38.9MHz ± 1.5 MHz Vi = 10mVrms (VIF input)
 - (3) Measure maximum and minimum AFT output voltage (at the measuring point B) by changing the input frequency.
 - (4) Maximum voltage: $V_{16}H$, minimum voltage: $V_{16}L$.



V20.V21.V22.V23. AFT tolerance 1,2,AFT detector sensitivity, AFT Dead Zone [dfa, Sf, fda]

(1) Measure the frequency deviation when the voltage at the measuring point B changes from V1 to V2. $\dots \Delta f$

$$Sf(mV/kHz) = \frac{V1-V2}{\Delta f}$$

- (2) Measure the width in which the voltage at the measuring point B does not change.
- (3) Calculate as follows:
- fda (kHz) = f2 f1
- (4) Calculate as follows:

IF Center frequency: 38.9MHz, 38MHz

dfa (kHz) = fc -
$$\frac{f1 + f2}{2}$$

V24.V25. APC pull-in range [fpu, fpl]

- (1) Internal AGC
- (2) FLL: Free
- (3) fp = 33MHz to 44MHz CW;10mVrms
- (4) Adjust the SG signal frequency to be higher than fp = 38.9MHz to bring the PLL to unlocked state. Note; The PLL is taken as in unlocked state when a beat signal appears at test point A.
- (5) When the SG signal frequency is lowered, the PLL is brought to locked state again. f1
- (6) Lower the SG signal frequency to bring the PLL to unlock state.
- (7) When the SG signal frequency is raised, the PLL is brought to locked state again. f2
- (8) Calculate as follows:
 - fpu = f1 38.9MHzfpl = f2 38.9MHz

V26.V27. VCO maximum variable range (U, L) [dfu, dfl]

- (1) Apply the V_{CC} voltage to the external AGC, IF AGC (pin 18).
- (2) fl is taken as the frequency when 1V is applied to the APC pin (pin 9). In the same manner, fu is taken as the frequency when 5V is applied to the APC pin (pin 9).
 dpu = fu 38.9MHz

dfl = fl - 38.9 MHz

V28. VCO control sensitivity [β]

- (1) Apply the V_{CC} voltage to the external AGC, IF AGC (pin 18).
- (2) Apply the 3V to the external FLL, FLL (pin 10).
- (3) Pick up the VCO oscillation frequency from the VIDEO output (A), GND, etc.
- And adjust the VCO coil so that the frequency becomes 38.9MHz.
- (4) f1 is taken as the frequency when 2.8V is applied to the APC pin (pin 9). In the same manner, f2 is taken as the frequency when 3.2V is applied to the APC pin (pin 9).

$$\beta = f2 - \frac{f1 - f2}{400} \quad (kHz/mV)$$

F1. 1st SIF conversion gain [VG]

(1) Internal AGC

- (2) fp = 38.9 MHz CW;10mV (VIF input)
 - $fs = 33.4 MHz CW;500 \mu V (1st SIF input) \cdots V1$
- (3) measure the detection output level at test point C (5.5MHz) \cdots V2

(4)
$$V_G = 20\log \frac{V_2}{V_1} dB$$

F2. 5.5MHz output level [So]

- (1) Internal AGC
- (2) fp = 38.9 MHz CW; 10mV (VIF input)
 - fs = 33.4MHz CW; 10mV (1st SIF input) V1
- (3) Measure the detection output level at test point C (5.5MHz). So (mVrms)

F3. 1st maximum input [Si max]

- (1) Internal AGC
- (2) fp = 38.9MHz CW; 10mV (VIF input)
 - fs = 33.4MHz CW; Variable (1st SIF input)
- (3) Input level at which the detection output (5.5MHz) at test point C becomes So $\pm 2dB$ Si max

F4.F5. 1st SIF input resistance, input capacitance [Ri (SIF1), Ci (SIF1)]

(1) Referring to the Input Impedance Test Circuit, measure Ri and Ci with an impedance analyzer.

S1. SIF Limiting sensitivity [Vi (lim)]

- (1) Apply the V_{CC} voltage to the external AGC, IF AGC (pin 18).
- (2) fs = 5.5MHz fm = 400Hz $\Delta F = \pm 300$ kHz (SIF input)
- (3) Set the SIF input level to 31.6mVrms and measure the level at test point D. \cdots V1
- (4) Lower the SIF input level and measure the input level which becomes V1. 3dB.

S2.S4. FM detection output voltage, total harmonics distortion [VO(FM), THD]

- (1) Apply the V_{CC} voltage to the external AGC, IF AGC (pin 18).
- (2) fs = 5.5MHz fm = 400Hz $\Delta f = \pm 30kHz$
 - (SIF input Vi = 31.6mVrms)
- (3) Measure the FM detection output voltage, total harmonics distortion at test point D.

S3. AM rejection ratio [AMR]

- (1) External AGC ($V_{18} = V_{CC}$)
- (2) fs = 5.5MHz fm = 400Hz AM = 30%
 - (SIF input Vi = 31.6mVrms)
- (3) Measure the output level at test point D. \cdots VAM

(4) AMR =
$$20\log \frac{V_O (DET)}{VAM} dB$$

S5. SIF S/N [S/N (FM)]

- (1) External AGC ($V_{15} = V_{CC}$)
- (2) fs = 5.5MHz NO MOD Vi = 31.6mVrms
- (3) Measure the output level at test point D. Vn

(4) S/N = 20log
$$\frac{V_O (DET)}{V_n} dB$$

S7.S8. PAL, NT de-emphasis [Pdeem, Ndeem]

- (1) External AGC ($V_{18} = V_{CC}$)
- (2) $fs = 5.5MHz fm = 3kHz \Delta F = \pm 30kHz$ (SIF input Vi = 31.6mVrms)
- (3) Open system switches (A (pin 13) and B (pin 14)). (BG mode)
- (4) Measure the FM detector output voltage at test point D. Vp
- (5) Calculate as follows:
- Pdeem (dB) = Vp VO (FM)
- (6) $fs = 4.5MHz fm = 2kHz \Delta F = \pm 30kHz$ (SIF input Vi = 31.6mVrms)
- (7) Set system switches [A (pin 13) and B (pin 14)] to GND. (NT mode)
- (8) Measure the FM detector output voltage at test point D. Vp
- (9) Calculate as follows: Ndeem (dB) = Vnt - VO (FM)

S9. PAL/NT Audio voltage gain difference [GD]

- (1) External AGC (V18 =VCC)
- (2) fs = 4.5MHz fm = 400Hz $\Delta F = \pm 30$ kHz
 - (SIF input Vi = 31.6mVrms)
- (3) Set system switches [A (pin 13) and B (pin 14)] to GND.
- (4) Measure the FM detector output voltage at test point D. Vnt
- (5) Calculate as follows:
 - GD(db) = Vnt VO(FM)

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